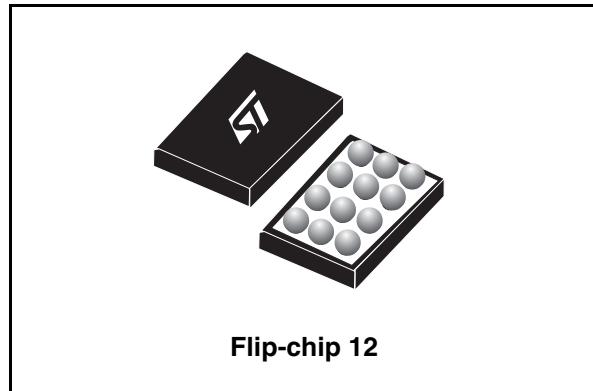


Low voltage 0.5 Ω dual SPDT switch with break-before-make feature and 15 kV ESD protection

Features

- Wide operating voltage range:
 V_{CC} (OPR) = 1.65 to 4.8 V
- Low power dissipation:
 I_{CC} = 0.2 μ A (max.) at T_A = 85 °C
- Low "ON" resistance:
 - R_{ON} = 0.75 Ω (T_A = 25 °C) at V_{CC} = 2.25 V
 - R_{ON} = 0.50 Ω (T_A = 25 °C) at V_{CC} = 3.0 V
 - R_{ON} = 0.40 Ω (T_A = 25 °C) at V_{CC} = 4.3 V
- Separate supply voltage for switch and control pin
- Latch-up performance exceeds 100 mA per JESD 78, Class II
- ESD performance tested on common pin (D pin):
 - 15 kV IEC-61000-4-2 ESD, contact discharge
 - 8 kV HBM JESD22 A114-B Class II
- ESD performance tested on S1 and S2 pin:
 - 8 kV IEC-61000-4-2 ESD, contact discharge
- ESD performance test on all other pins:
 - 4 kV HBM (JESD22 A114-B Class II)
 - 400 V machine model (JESD22 A115-A)
 - 1500 V charged-device model (JESD22 C101)



Description

The STG4260 is a high-speed CMOS low voltage dual analog SPDT (single pole dual throw) switch or 2:1 multiplexer/demultiplexer switch fabricated in silicon gate C²MOS technology. It is designed to operate from 1.65 V to 4.8 V, making this device ideal for portable applications. It offers low ON-resistance (0.40 Ω typ.) at V_{CC} = 4.3 V. The SEL inputs are provided to control the switches.

The switch S1 is ON (connected to common port D) when the SEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common Port D) when the SEL input is held low and OFF (high impedance state exists between the two ports) when SEL is held high.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Applications

- Mobile phones

Table 1. Device summary

| Order code | Package | Packing |
|------------|--------------|---------------|
| STG4260BJR | Flip-chip 12 | Tape and reel |

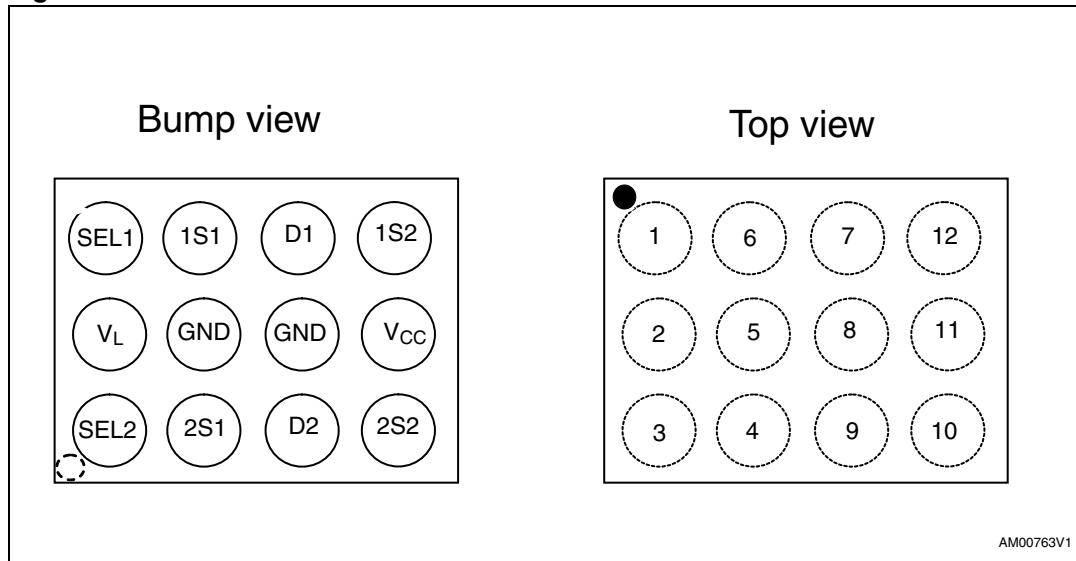
Contents

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1 Pin settings

1.1 Pin connections

Figure 1. Pin connection



1.2 Pin description

Table 2. Pin assignment

| Pin number | Symbol | Name and function |
|------------|--------|----------------------------------|
| 1 | SEL2 | Selection control for switch 2 |
| 2 | VL | Logic supply voltage |
| 3 | SEL1 | Selection control for switch 1 |
| 4 | 1S1 | Independent channel for switch 1 |
| 5 | GND | Ground (0 V) |
| 6 | 2S1 | Independent channel for switch 2 |
| 7 | D2 | Common channel for switch 2 |
| 8 | GND | Ground (0 V) |
| 9 | D1 | Common channel for switch 1 |
| 10 | 1S2 | Independent channel for switch 1 |
| 11 | VCC | Positive supply voltage |
| 12 | 2S2 | Independent channel for switch 2 |

2 Logic diagram

Figure 2. Functional diagram

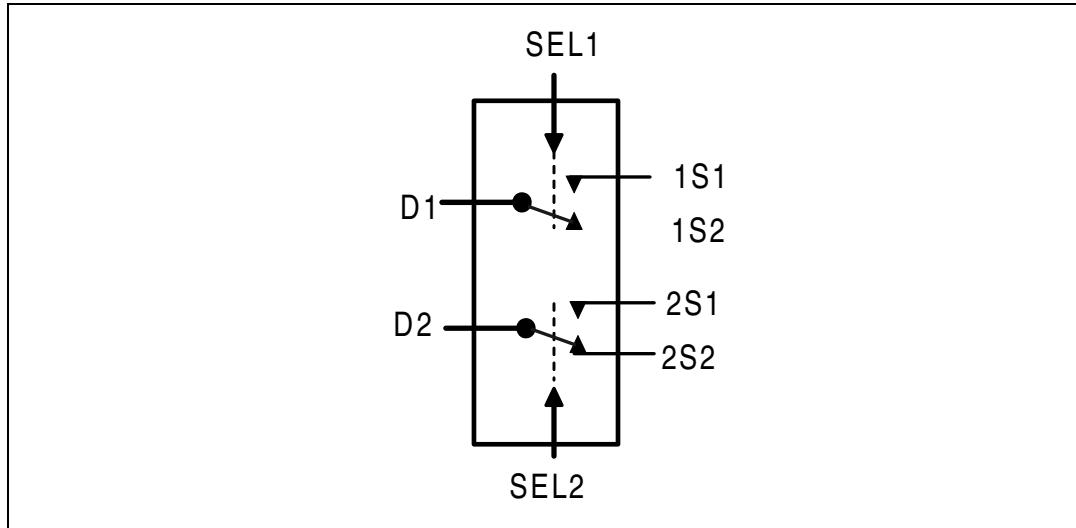


Figure 3. Circuit equivalent logic

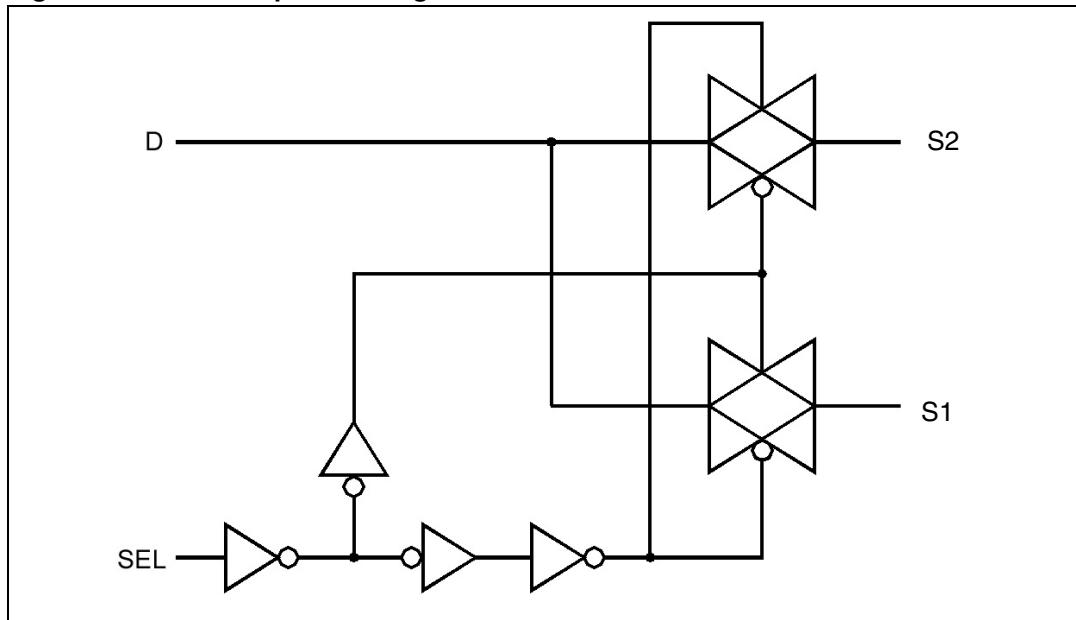


Table 3. Truth table

| SEL | Switch S1 | Switch S2 |
|-----|--------------------|--------------------|
| H | ON | OFF ⁽¹⁾ |
| L | OFF ⁽¹⁾ | ON |

1. High impedance

3 Maximum ratings

Stressing the device above the rating listed in the “Absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute maximum rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-----------------------|--------------------------------------------------------------|------------------------|------------------|
| V_{CC} | Supply voltage | -0.5 to 5.5 | V |
| V_L | Logic supply voltage | -0.5 to 5.5 | V |
| V_I | DC input voltage | -0.5 to $V_{CC} + 0.5$ | V |
| V_{IC} | DC control input voltage | -0.5 to $V_L + 5.5$ | V |
| V_O | DC output voltage | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IKC} | DC input diode current on control pin ($V_{SEL} < 0$ V) | - 50 | mA |
| I_{IK} | DC input diode current ($V_{SEL} < 0$ V) | ± 50 | mA |
| I_{OK} | DC output diode current | ± 20 | mA |
| I_O | DC output current | ± 300 | mA |
| I_{OP} | DC output current peak (pulse at 1ms, 10% duty cycle) | ± 500 | mA |
| I_{CC} or I_{GND} | DC V_{CC} or ground current | ± 100 | mA |
| P_D | Power dissipation at $T_A = 70^\circ\text{C}$ ⁽¹⁾ | 500 | mW |
| T_{stg} | Storage temperature | -65 to 150 | $^\circ\text{C}$ |
| T_L | Lead temperature (10 sec) | 260 | $^\circ\text{C}$ |

1. Derate above 70 $^\circ\text{C}$ by 18.5 mW/C

Table 5. Recommended operating conditions

| Symbol | Parameter | Value | Unit |
|----------|----------------------------------------|-----------------------|------------------|
| V_{CC} | Supply voltage | 1.65 to 4.8 | V |
| V_L | Logic supply voltage ⁽¹⁾ | 1.65 to V_{CC} | V |
| V_I | Input voltage | 0 to V_{CC} | V |
| V_{IC} | Control input voltage | 0 to V_L | V |
| V_O | Output voltage | 0 to V_{CC} | V |
| T_{op} | Operating temperature | -40 to 85 | $^\circ\text{C}$ |
| dt/dv | Input rise and fall time control input | $V_L = 1.65$ to 2.7 V | 0 to 20 |
| | | $V_L = 3.0$ to 4.8 V | 0 to 10 |
| | | | ns/V |

1. V_L pin should not be left floating.

4 Electrical characteristics

Table 6. DC specifications

| Symbol | Parameter | V _{CC} (V) | V _L (V) | Test condition | Value | | | | | Unit | |
|-------------------|-----------------------------------------------------|---------------------|--------------------|--------------------------------------------------------------------|------------------------|------|------|--------------|------|------|--|
| | | | | | T _A = 25 °C | | | -40 to 85 °C | | | |
| | | | | | Min | Typ | Max | Min | Max | | |
| V _{IH} | High level input voltage | 1.65 – 4.3 | 1.65 – 1.95 | | 1.25 | – | – | 1.25 | – | V | |
| | | | 2.3 – 2.7 | | 1.75 | – | – | 1.75 | – | | |
| | | | 3.0 – 3.6 | | 2.34 | – | – | 2.34 | – | | |
| | | | 4.3 | | 2.80 | – | – | 2.80 | – | | |
| V _{IL} | Low level input voltage | 1.65 – 4.3 | 1.65 – 1.95 | | – | – | 0.6 | – | 0.6 | V | |
| | | | 2.3 – 2.7 | | – | – | 0.8 | – | 0.8 | | |
| | | | 3.0 – 3.6 | | – | – | 1.05 | – | 1.05 | | |
| | | | 4.3 | | – | – | 1.5 | – | 1.5 | | |
| R _{ON} | ON resistance | 1.8 | 1.65 – 4.3 | V _S = 0 V to V _{CC} I _S = 100 mA | – | 1.5 | 2.5 | – | 3.7 | Ω | |
| | | 2.25 | | | – | 0.75 | 1.0 | – | 1.3 | | |
| | | 3 | | | – | 0.50 | 0.65 | – | 0.8 | | |
| | | 3.7 | | | – | 0.45 | 0.55 | – | 0.7 | | |
| | | 4.3 | | | – | 0.40 | 0.50 | – | 0.65 | | |
| ΔR _{ON} | ON resistance match between channels ⁽¹⁾ | 1.8 | 1.65 – 4.3 | V _S = 0 V to V _{CC} I _S = 100 mA | – | 40 | – | – | – | mΩ | |
| | | 2.25 | | | – | 20 | – | – | – | | |
| | | 3 | | | – | 10 | – | – | – | | |
| | | 3.7 | | | – | 10 | – | – | – | | |
| | | 4.3 | | | – | 10 | – | – | – | | |
| R _{FLAT} | ON resistance flatness ⁽²⁾ | 1.8 | 1.65 – 4.3 | V _S = 0 V to V _{CC} I _S = 100 mA | – | 1000 | 1700 | – | 2000 | mΩ | |
| | | 2.25 | | | – | 300 | 430 | – | 550 | | |
| | | 3 | | | – | 170 | 220 | – | 270 | | |
| | | 3.7 | | | – | 160 | 210 | – | 270 | | |
| | | 4.3 | | | – | 160 | 210 | – | 270 | | |
| I _{OFF} | Sn OFF state leakage current | 4.3 | 4.3 | V _S = 0.3 to 4.0 V _D = 0.3 to 4.0 | -30 | – | 30 | -300 | 300 | nA | |
| I _{ON} | Sn ON state leakage current | 4.3 | 4.3 | V _S = 0.3 to 4.0 V _D = open | -30 | – | 30 | -300 | 300 | nA | |
| I _D | D ON state leakage current | 4.3 | 4.3 | V _S = open V _D = 0.3 to 4.0 | -30 | – | 30 | -300 | 300 | nA | |

Table 6. DC specifications (continued)

| Symbol | Parameter | V _{CC} (V) | V _L (V) | Test condition | Value | | | | | Unit | |
|------------------|--------------------------|---------------------|--------------------|-------------------------------------------|------------------------|-----|------|--------------|-----|------|--|
| | | | | | T _A = 25 °C | | | -40 to 85 °C | | | |
| | | | | | Min | Typ | Max | Min | Max | | |
| I _{CC} | Quiescent supply current | 1.65 – 4.3 | 1.65 – 4.3 | V _{SEL} = V _{CC} or GND | -0.05 | – | 0.05 | -0.2 | 0.2 | µA | |
| I _{SEL} | SEL leakage current | 1.65 – 4.3 | 1.65 – 4.3 | V _{SEL} = 4.3V or GND | -0.2 | – | 0.2 | -2 | 2 | µA | |

1. $\Delta R_{ON} = R_{ON(\text{Max})} - R_{ON(\text{Min})}$

2. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Table 7. AC electrical characteristics (C_L = 35 pF, R_L = 50 Ω, t_r = t_f ≤ 5 ns)

| Symbol | Parameter | V _{CC} (V) | V _L (V) | Test conditions | Value | | | | | Unit | |
|-------------------------------------|------------------------------|---------------------|--------------------|----------------------------------------------------------------------------------------|------------------------|------|-----|--------------|-----|------|--|
| | | | | | T _A = 25 °C | | | -40 to 85 °C | | | |
| | | | | | Min | Typ | Max | Min | Max | | |
| t _{PLH} , t _{PHL} | Propagation delay | 1.65 – 1.95 | 1.65 – 4.3 | | – | 0.18 | – | – | – | ns | |
| | | 2.3 – 2.7 | | | – | 0.14 | – | – | – | | |
| | | 3.0 – 3.3 | | | – | 0.12 | – | – | – | | |
| | | 3.6 – 4.3 | | | – | 0.12 | – | – | – | | |
| t _{ON} | TURN-ON time | 1.65 – 1.95 | 1.65 – 4.3 | V _S = V _{CC} R _L = 50 Ω C _L = 30 pF | – | 70 | 123 | – | 160 | ns | |
| | | 2.3 – 2.7 | | | – | 48 | 62 | – | 80 | | |
| | | 3 – 3.6 | | | – | 33 | 43 | – | 56 | | |
| | | 4.3 | | | – | 29 | 38 | – | 49 | | |
| t _{OFF} | TURN-OFF time | 1.65 – 1.95 | 1.65 – 4.3 | V _S = V _{CC} R _L = 50 Ω C _L = 30 pF | – | 36 | 45 | – | 60 | ns | |
| | | 2.3 – 2.7 | | | – | 35 | 47 | – | 62 | | |
| | | 3 – 3.6 | | | – | 30 | 40 | – | 51 | | |
| | | 4.3 | | | – | 29 | 38 | – | 50 | | |
| t _D | Break-before-make time delay | 1.65 – 1.95 | 1.65 – 4.3 | C _L = 35 pF R _L = 50 Ω V _S = V _{CC} /2 | 10 | 42 | – | – | – | ns | |
| | | 2.3 – 2.7 | | | 10 | 22 | – | – | – | | |
| | | 3 – 3.6 | | | 5 | 15 | – | – | – | | |
| | | 4.3 | | | 5 | 12 | – | – | – | | |

Table 7. AC electrical characteristics ($C_L = 35 \text{ pF}$, $R_L = 50 \Omega$, $t_r = t_f \leq 5 \text{ ns}$) (continued) (continued)

| Symbol | Parameter | V_{CC} (V) | V_L (V) | Test conditions | Value | | | | | Unit | |
|--------|-------------------------------|-----------------|--------------|-----------------------------------------------------------------------------------------------------------------|--------------------------|------|-----|------------------------------------|-----|------|--|
| | | | | | $T_A = 25^\circ\text{C}$ | | | $-40 \text{ to } 85^\circ\text{C}$ | | | |
| | | | | | Min | Typ | Max | Min | Max | | |
| Q | Charge injection | 1.65 – 1.95 | 1.65-4.3 | $C_L = 1\text{nF}$ $V_{GEN} = 0 \text{ V}$ | – | 83 | – | – | – | pC | |
| | | 2.3 – 2.7 | | | – | 98 | – | – | – | | |
| | | 3.0 – 3.3 | | | – | 114 | – | – | – | | |
| | | 3.6 – 4.3 | | | – | 140 | – | – | – | | |
| OIRR | Off isolation ⁽¹⁾ | 1.65 – 4.3 | 4.3 | $V_S = 1V_{RMS}$ $f = 100 \text{ kHz}$ | – | 77 | – | – | – | dB | |
| | | | | $V_S = 1V_{RMS}$ $f = 1 \text{ MHz}$ | – | 67 | – | – | – | | |
| | | | | $V_S = 1V_{RMS}$ $f = 5 \text{ MHz}$ | – | 50 | – | – | – | | |
| Xtalk | Crosstalk | 1.65 – 4.3 | 4.3 | $V_S = 1V_{RMS}$ $f = 100 \text{ kHz}$ | – | 80 | – | – | – | dB | |
| | | | | $V_S = 1V_{RMS}$ $f = 1 \text{ MHz}$ | – | 67 | – | – | – | | |
| | | | | $V_S = 1V_{RMS}$ $f = 5 \text{ MHz}$ | – | 50 | – | – | – | | |
| THD | Total harmonic distortion | 2.3 – 4.3 | 4.3 | $R_L = 600 \Omega$ $C_L = 50 \text{ pF}$ $V_S = V_{CC} V_{PP}$ $f = 600 \text{ Hz to } 20 \text{ kHz}$ | – | 0.01 | – | – | – | % | |
| BW | -3dB bandwidth (switch ON) | 1.65 – 4.3 | 4.3 | $R_L = 50 \Omega$ | – | 50 | – | – | – | MHz | |

1. OFF-isolation = $20 \log_{10} (V_D/V_S)$, V_D = output, V_S = input to off switch

Table 8. Capacitive characteristics

| Symbol | Parameter | V _{CC} (V) | V _L (V) | Test condition | Value | | | | | Unit | |
|------------------|--------------------------------------------------------|------------------------|-----------------------|----------------------------------|------------------------|-----|-----|--------------|-----|------|--|
| | | | | | T _A = 25 °C | | | -40 to 85 °C | | | |
| | | | | | Min | Typ | Max | Min | Max | | |
| C _{SEL} | Control pin input capacitance | 1.8 – 4.3 | 1.8 – 4.3 | V _L = V _{CC} | – | 30 | – | – | – | pf | |
| C _{SN} | S _n port capacitance | 1.8 – 4.3 | 1.8 – 4.3 | V _L = V _{CC} | – | 94 | – | – | – | pf | |
| C _D | D port capacitance when the switch is enabled | 1.8 – 4.3 | 1.8 – 4.3 | V _L = V _{CC} | – | 227 | – | – | – | pf | |

5 Test circuits

Figure 4. ON resistance

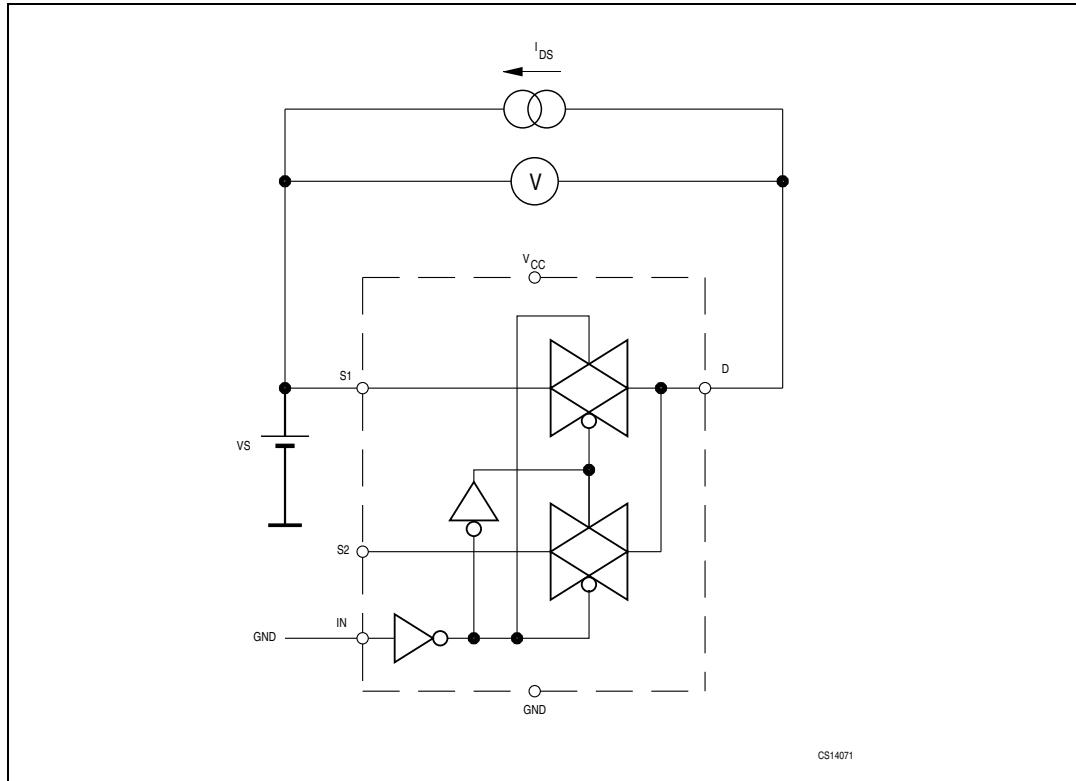


Figure 5. Bandwidth

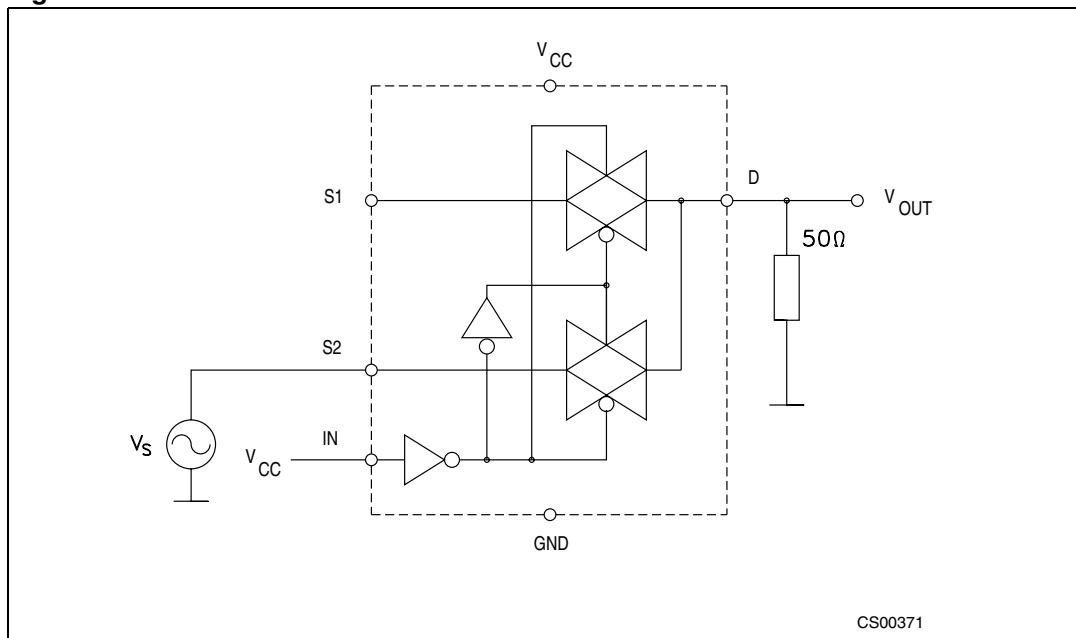


Figure 6. OFF leakage

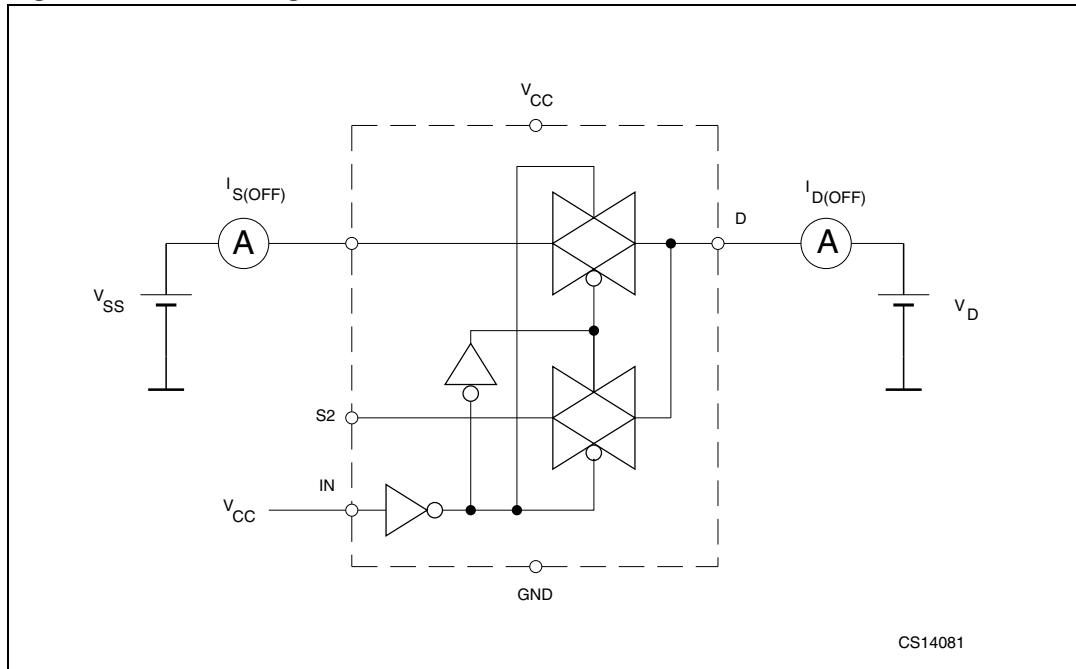


Figure 7. Channel-to-channel crosstalk

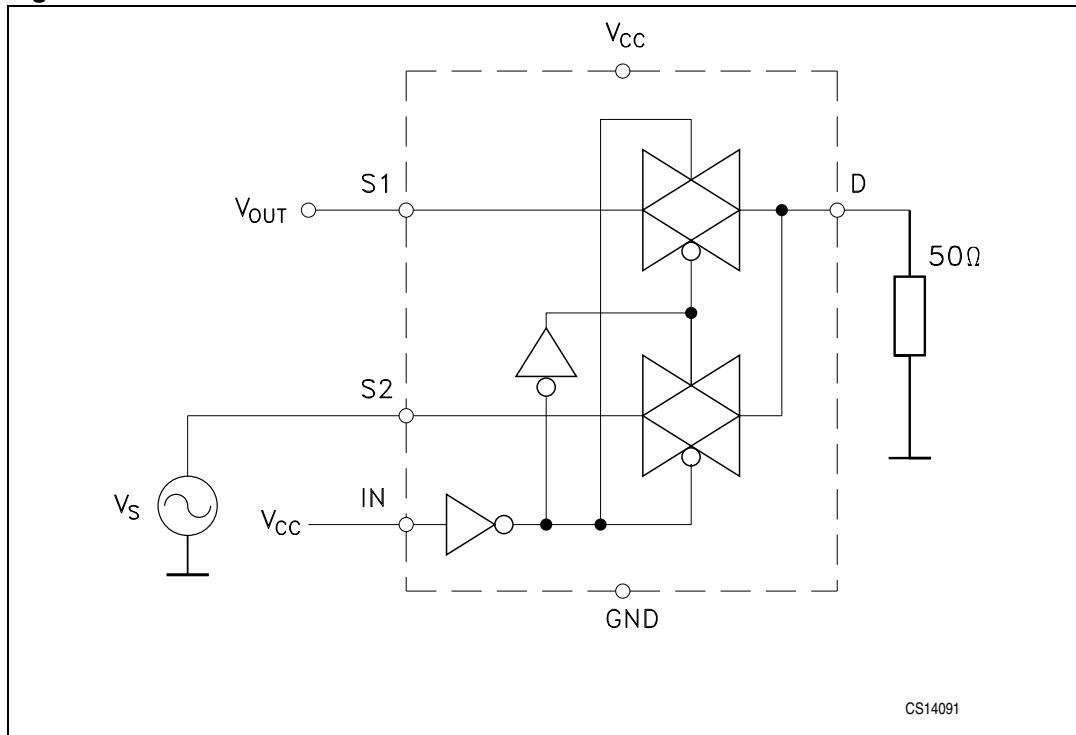


Figure 8. OFF isolation

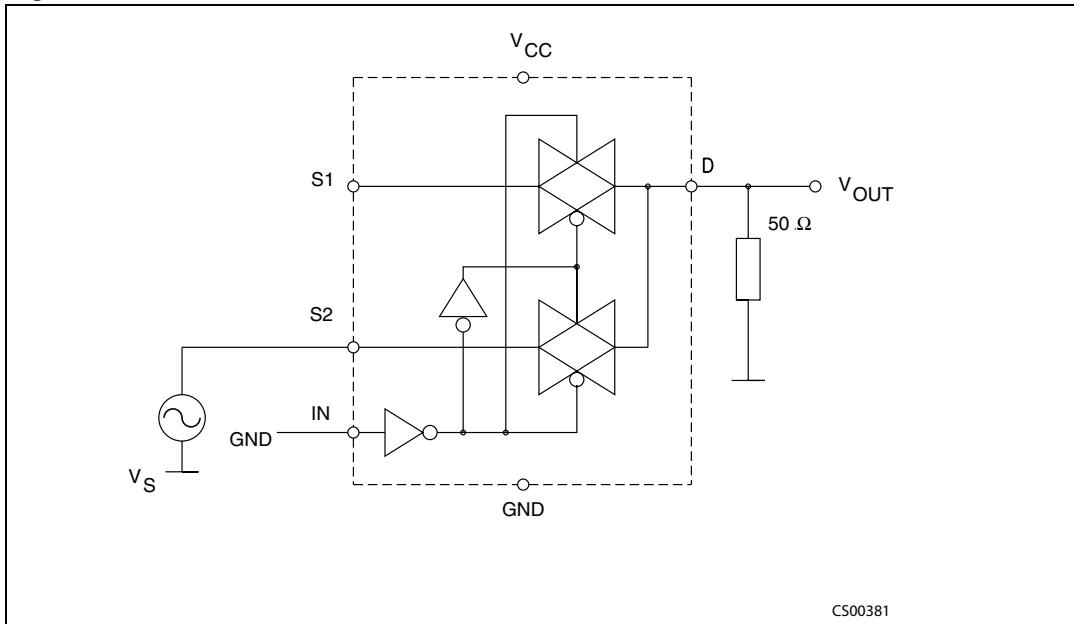
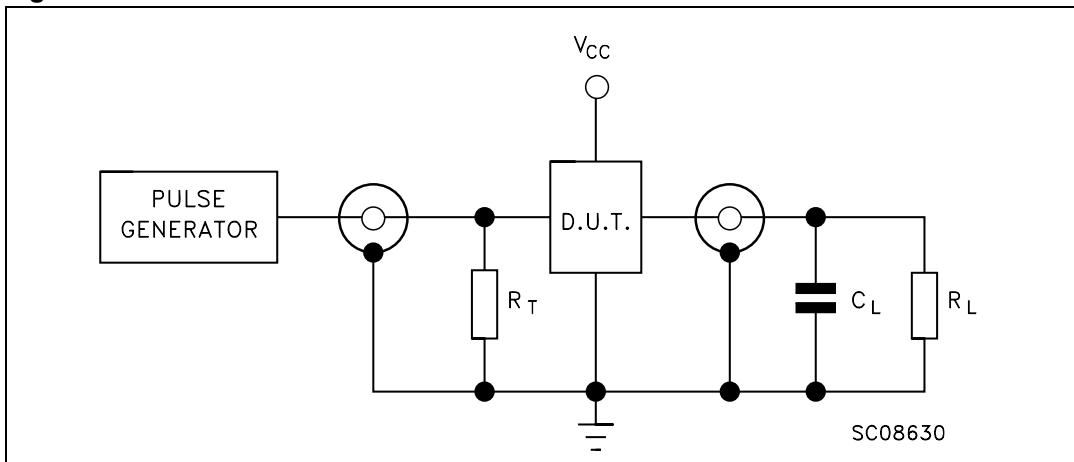


Figure 9. Test circuit



1. $C_L = 5/35 \text{ pF}$ or equivalent: (includes jig capacitance)
2. $R_L = 50 \Omega$ or equivalent
3. $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 10. Break-before-make time delay

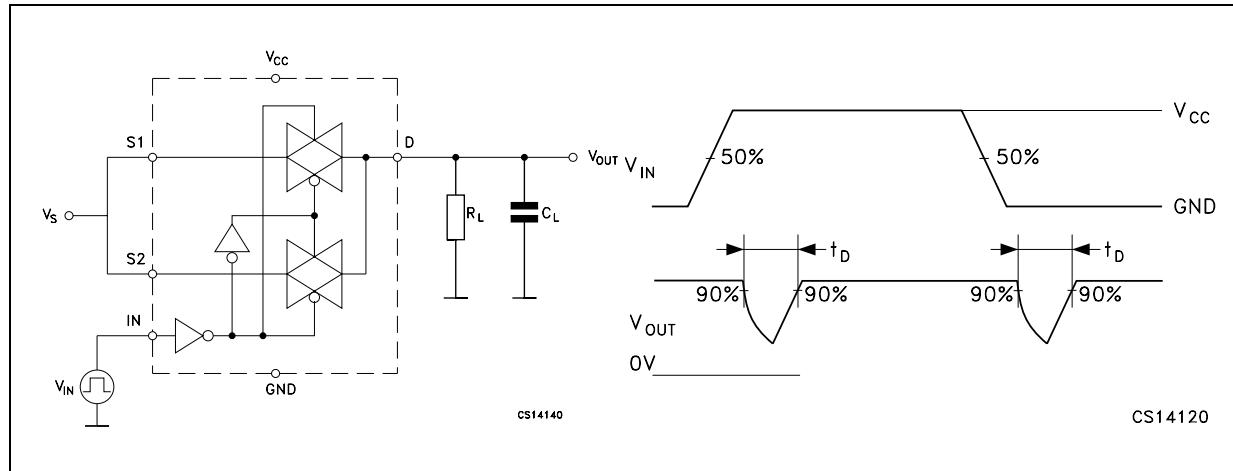


Figure 11. Switching time and charge injection
 $(V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega, R_L = 1 \text{ M}\Omega, C_L = 100 \text{ pF})$

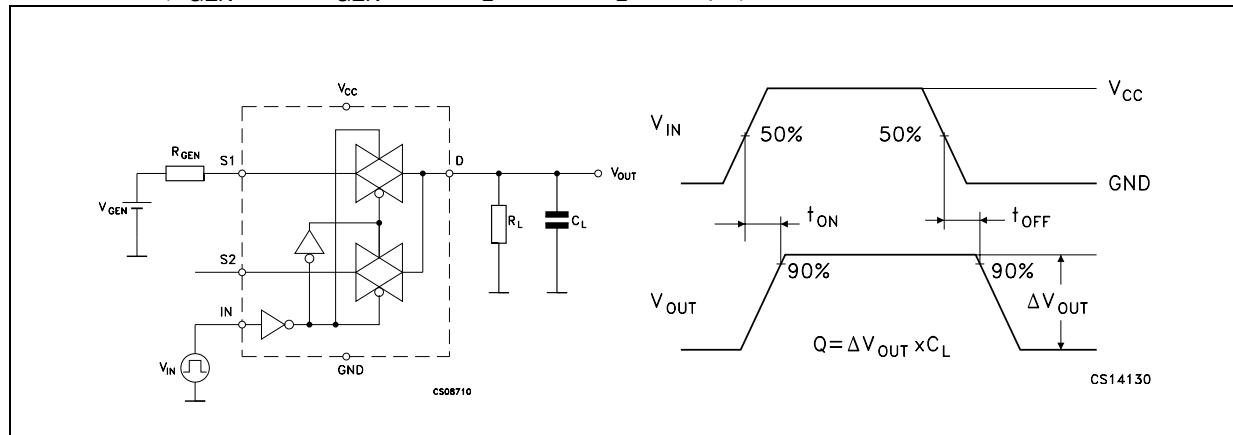
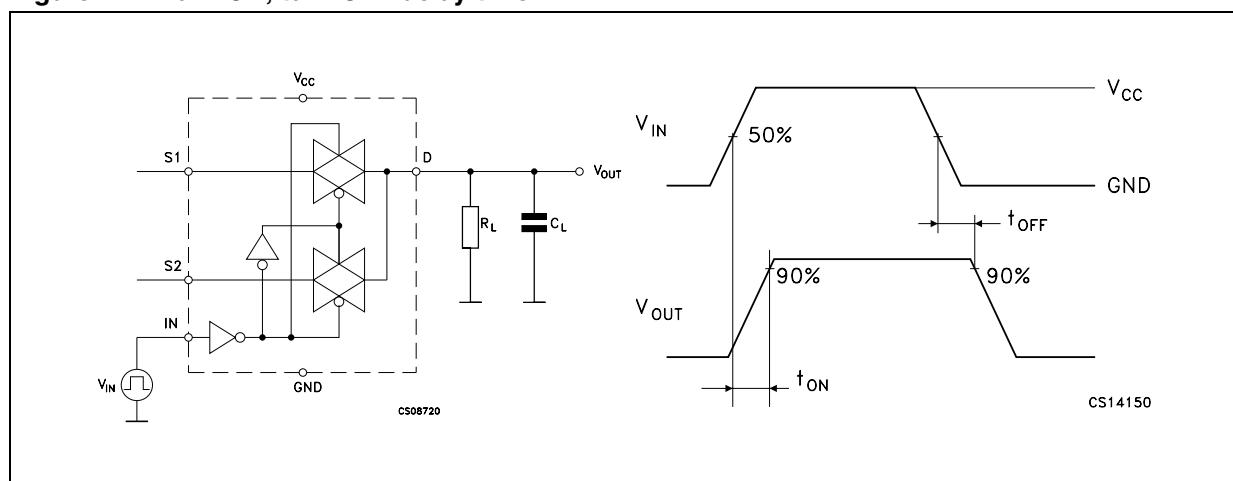


Figure 12. Turn ON, turn OFF delay time



6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Figure 13. Package outline for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch

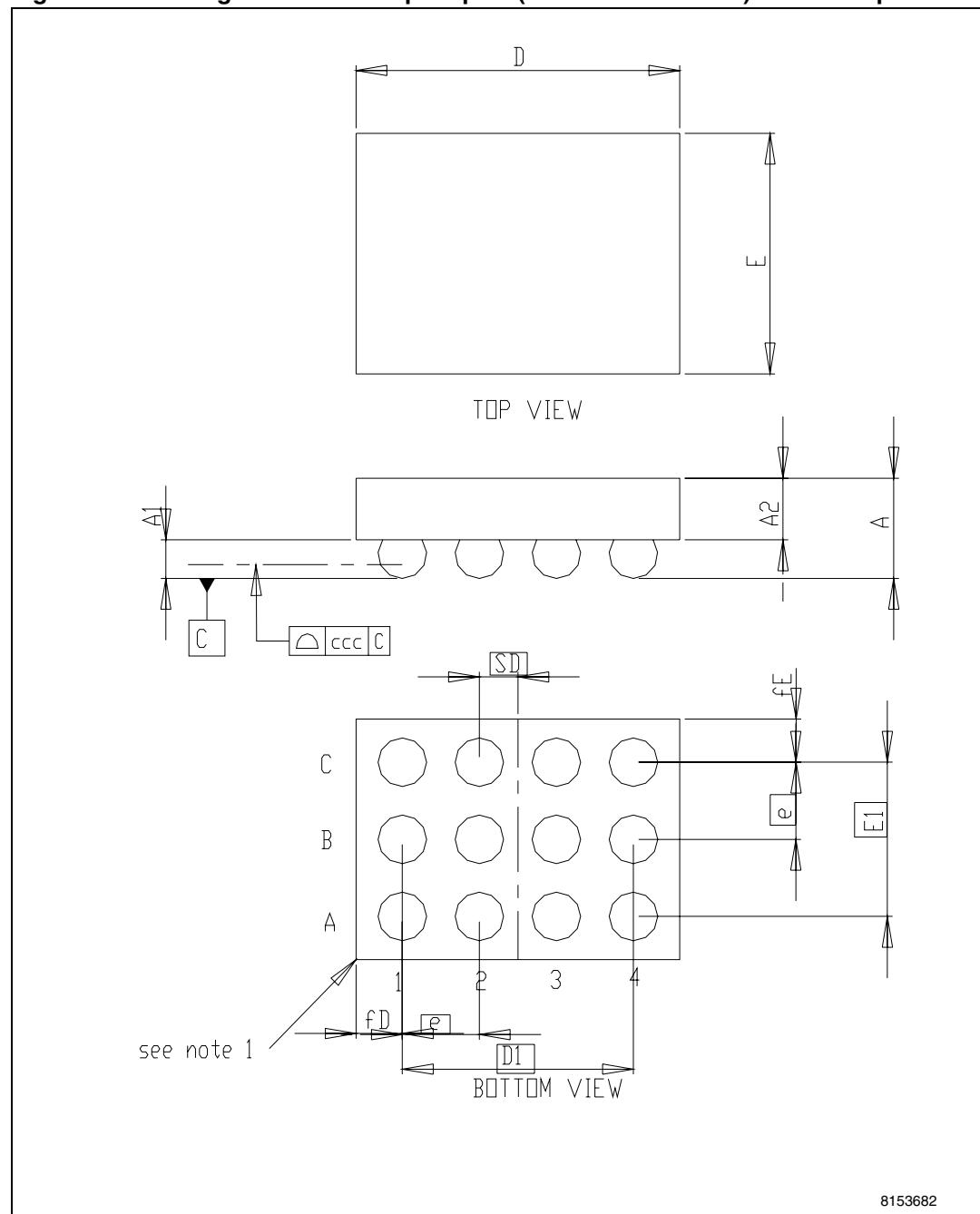


Table 9. Mechanical data for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch

| Symbol | Millimeters | | |
|--------|-------------|-------|-------|
| | Min | Typ | Max |
| A | 0.535 | 0.58 | 0.625 |
| A1 | 0.18 | 0.205 | 0.23 |
| A2 | 0.355 | 0.375 | 0.395 |
| b | 0.215 | 0.255 | 0.295 |
| D | 1.85 | 1.9 | 1.95 |
| D1 | — | 1.5 | — |
| e | 0.45 | 0.5 | 0.55 |
| E | 1.35 | 1.4 | 1.45 |
| E1 | — | 1 | — |
| SD | — | 0.25 | — |
| f | 0.19 | 0.2 | 0.21 |
| ccc | — | 0.08 | — |

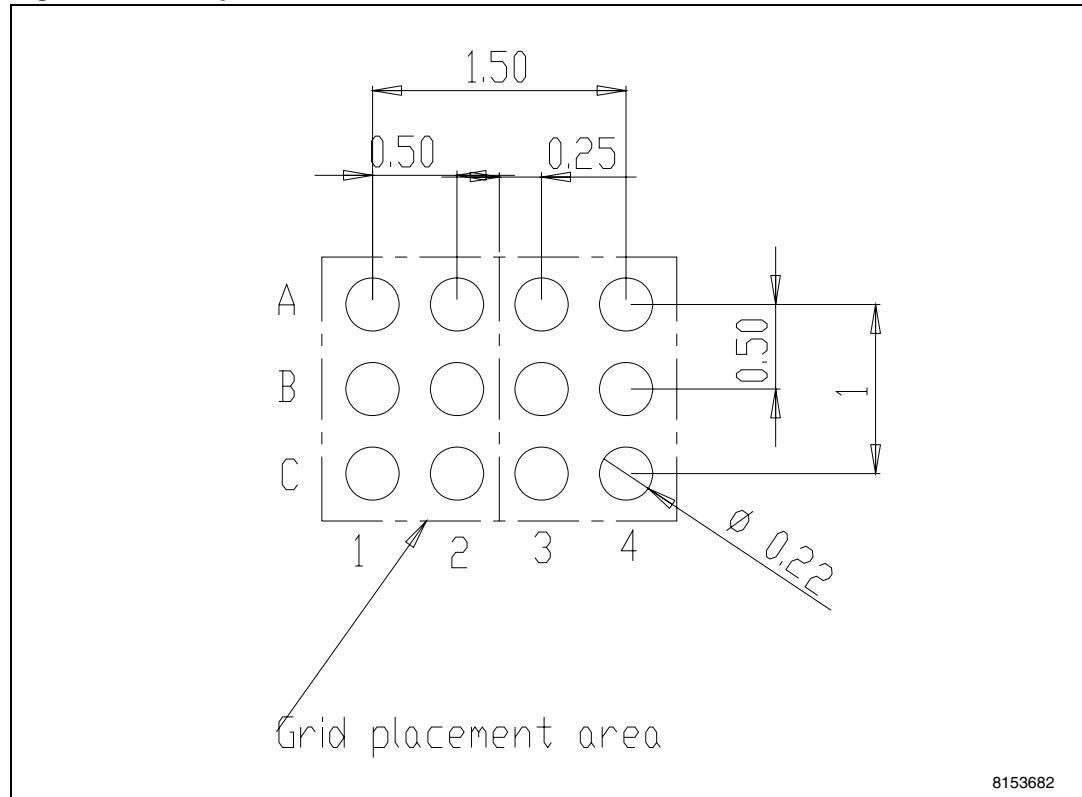
Figure 14. Footprint recommendation

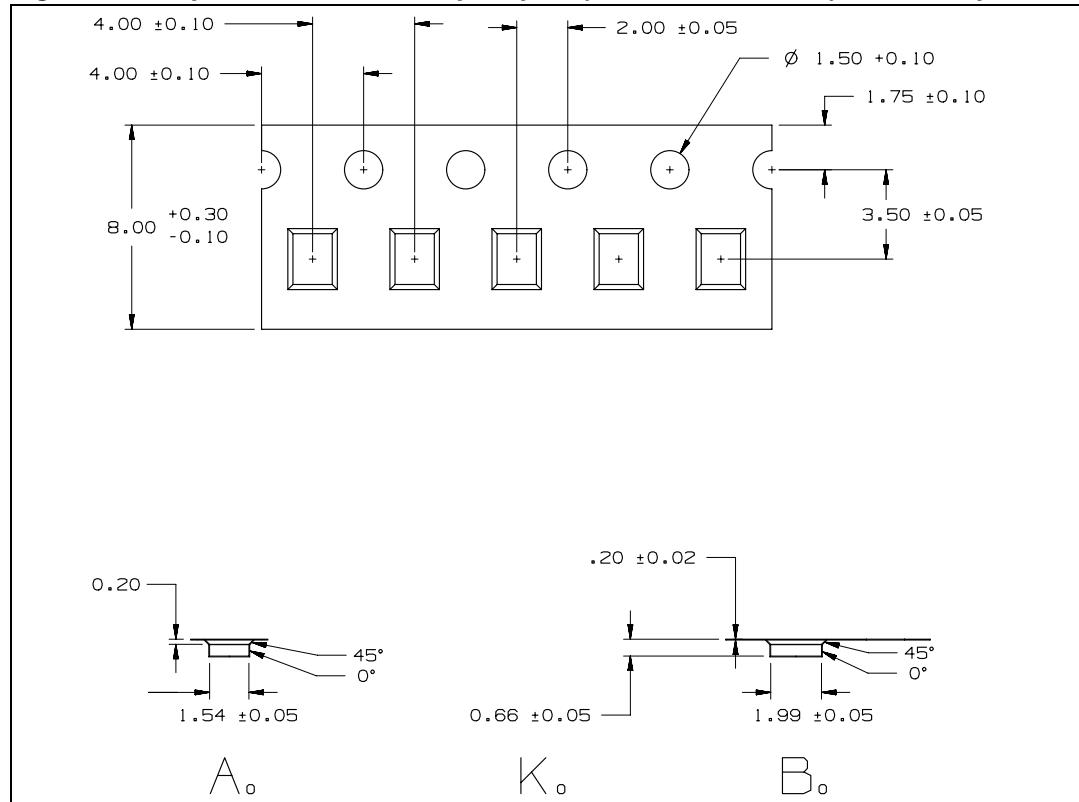
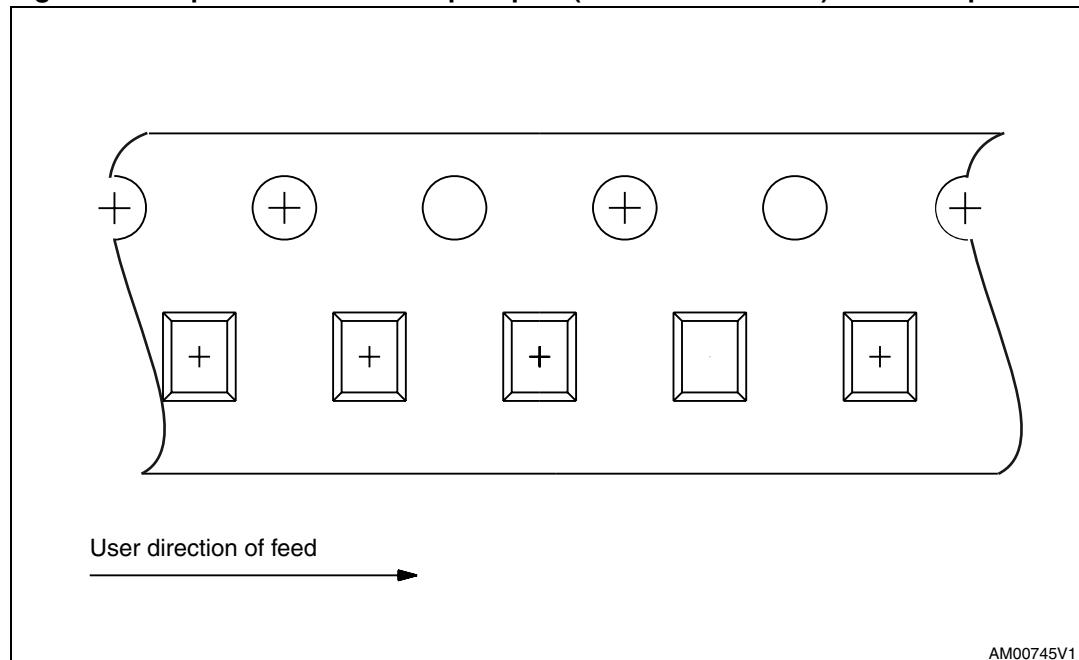
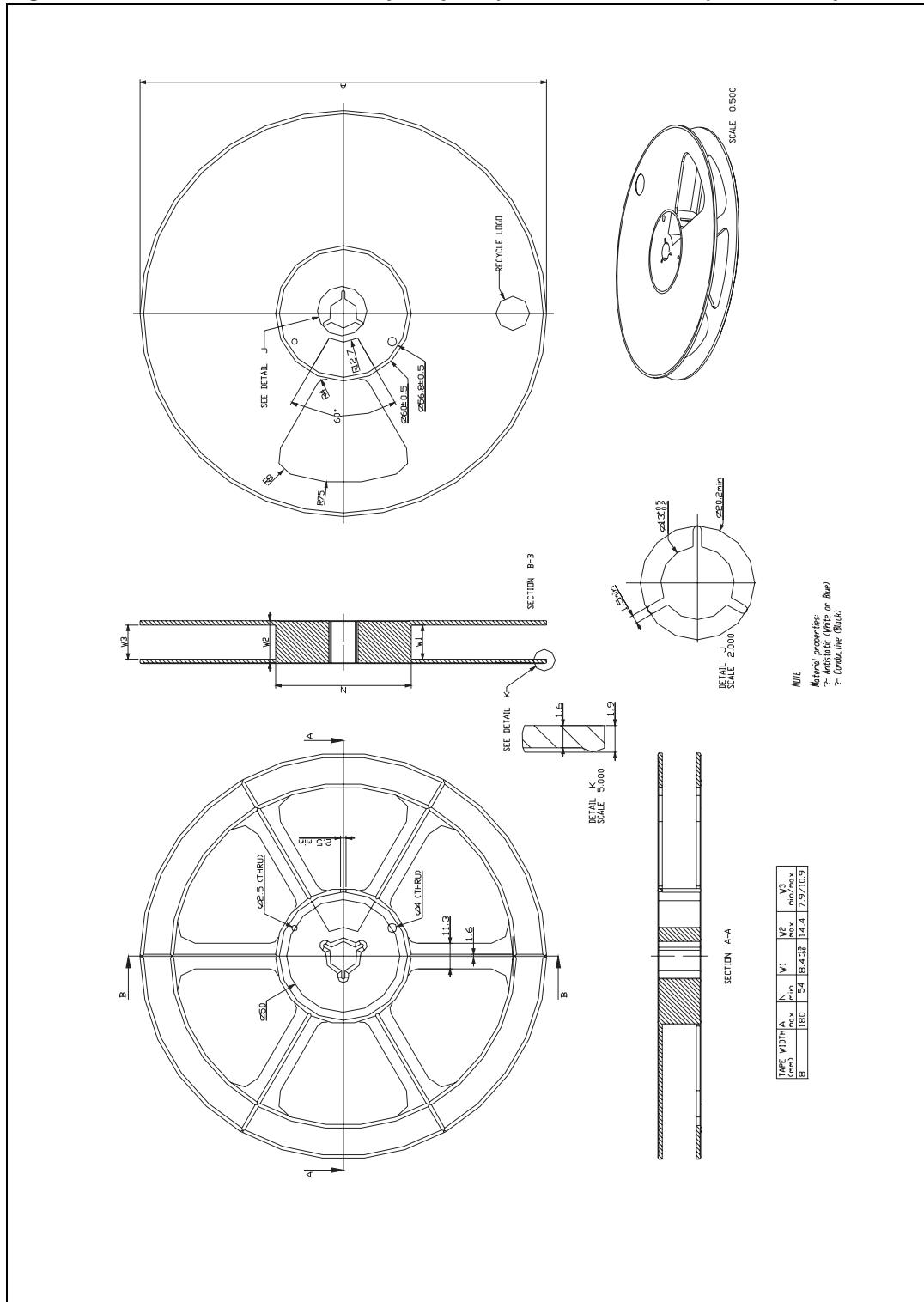
Figure 15. Tape information for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch**Figure 16. Tape orientation for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch**

Figure 17. Reel information for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch



7 Revision history

Table 10. Document revision history

| Date | Revision | Changes |
|-------------|----------|----------------------------------------------------------------------------------------------------------------------------------------------|
| 19-Nov-2008 | 1 | Initial release. |
| 20-Apr-2009 | 2 | Document status promoted from preliminary data to datasheet. Modified: <i>Table 6: DC specifications on page 6</i> and <i>Section 6</i> . |

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